UNCLA	SSIFIE		CONTROL USING ARDS OF			F/G 1	779	NL	



SUBJECT A SECONDER MARKER SECOND

DTE FILE COPY

047

AD-A180

RADC-TR-86-115 Final Technical Report October 1986



DYNAMIC CONTROL OF THE INPUT IMPEDANCE OF MICROSTRIP ELEMENTS USING REACTIVE LOADS

University of Houston

William F. Richards



APPROVED FOR PUBLIC RELEASE; DISTRIBUTION UNLIMITED

ROME AIR DEVELOPMENT CENTER Air Force Systems Command Griffiss Air Force Base, NY 13441-5700

This report has been reviewed by the RADC Public Affairs Office (PA) and is releasable to the National Technical Information Service (NTIS). At NTIS it will be releasable to the general public, including foreign nations.

RADC-TR-86-115 has been reviewed and is approved for publication.

APPROVED:

John R Corneil

JOHN R. CORNEIL, 2LT, USAF Project Engineer

APPROVED:

alan Chur

ALLAN C. SCHELL Directorate of Electromagnetic Sciences

FOR THE COMMANDER:

John a. Retz

JOHN A. RITZ Directorate of Plans & Programs

If your address has changed or if you wish to be removed from the RADC mailing list, or if the addressee is no longer employed by your organization, please notify RADC (EECS) Hanscom AFB MA 01731-5000. This will assist us in maintaining a current mailing list.

Do not return copies of this report unless contractual obligations or notices on a specific document requires that it be returned.

		REPORT DOCU	MENTATION	PAGE			
a. REPORT SECURITY CLASSIFICAT	TION		16. RESTRICTIVE	MARKINGS			
UNCLASSIFIED	N/A						
a. SECURITY CLASSIFICATION AU		AVAILABILITY O					
N/A b. DECLASSIFICATION / DOWNGR/		or public re	elease; di	stribution			
N/A	unlimited.						
PERFORMING ORGANIZATION F	5. MONITORING ORGANIZATION REPORT NUMBER(S)						
N/A	RADC-TR-86-115						
			1				
6a. NAME OF PERFORMING ORGANIZATION 65. OFFICE SYMBOL (If applicable)			7a. NAME OF MONITORING ORGANIZATION				
University of Houston	1		Rome Air Development Center (EECS)				
c. ADDRESS (City, State, and ZIP)	Code)		75. ADDRESS (C	ty, State, and ZIP	Code)		
Houston TX 77004			Hanscom AF	B MA 01731-5	6000		
HOUSEON IX //004							
Ja. NAME OF FUNDING / SPONSOR ORGANIZATION	ING	8b. OFFICE SYMBOL (If applicable)		T INSTRUMENT ID	ENTIFICATION	NUMBER	
Rome Air Development	Center	EECS	F30602-81-C-0193				
c. ADDRESS (City, State, and ZIP C	iode)	_ <u></u>	10. SOURCE OF	FUNDING NUMBER	RS	<u>-</u>	
-			PROGRAM	PROJECT	TASK	WORK UNIT	
Hanscom AFB MA 01731-	-5000		ELEMENT NO.	NO. 4600	NO.	ACCESSION NO	
			62702F	4600	- 13	F9	
3a. TYPE OF REPORT	136. TIME (FROM _L			ORT (Year, Month, er 1986	Day) 15 PA	GE COUNT 48	
2. PERSONAL AUTHOR(S) William F. Richards 3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION		COVERED 10 85_ 10 Sep 85			Day) 15. PA		
3a. TYPE OF REPORT Final					Day) 15. PA		
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION	FROME		Octob	er 1986	<u> </u>	48	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S	FROME	n 85 to Sep 85 18 SUBJECT TERMS Dynamic Impe	Octob Continue on reven dance Tuning	er 1986 se if necessary and	<u> </u>	48	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09	FROM Ja	n <u>85_70 Sep_85</u> 18 SUBJECT TERMS →Dynamic Impe Microstrip E	Octob Continue on rever dance Tuning lements	er 1986 se if necessary and	<u> </u>	48	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14	FROM J	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array	Continue on rever dance Tuning lements s , 4	er 1986 se if necessary and	<u> </u>	48	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever	FROM S UB-GROUP	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block	(Continue on rever dance Tuning lements s , C	er 1986 se if necessary and	d identify by b	48 block number)	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been	FROM S UB-GROUP se if necessary n expended	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block t o develop MMI	Continue on rever dance Tuning lements s , C number) C modules fo	er 1986 se if necessary and r active ape	d identify by t	48 Nock number) Sed array	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for	FROM S UB-GROUP se if necessary n expended motivation space, at	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work borne and grout	Continue on rever dance Tuning lements s , C number) C modules fo is to reduc nd based app	er 1986 se if necessary and r active ape e the size, lications.	d identify by the erture pha complexit Unfortuna	48 Nock number) sed array y and cost tely, a large	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been	FROM S UB-GROUP se if necessary n expended motivation space, at	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work borne and grout	Continue on rever dance Tuning lements s , C number) C modules fo is to reduc nd based app	er 1986 se if necessary and r active ape e the size, lications.	d identify by the erture pha complexit Unfortuna	48 Nock number) sed array y and cost tely, a large	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a f	FROM FROM Se if necessary n expended motivation space, at out impedate ferrite cit	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work borne and group ance occurs when broulator is ins	Continue on rever dance Tuning lements s , C number) C modules fo is to reduc nd based app the array i erted betwee	er 1986 r active ape e the size, lications. s scanned. n the module	d identify by the erture pha complexit Unfortuna To isolat e and the	48 Nock number) sed array y and cost tely, a large e the module antenna	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a f element. The inserts	FROM FROM Se if necessary n expended motivation space, at out impeda ferrite cition of the	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work borne and grout ance occurs when irculator is ins c circulator is	Continue on rever dance Tuning lements s , C number) C modules fo is to reduc nd based app the array i erted betwee in direct co	er 1986 r active ape e the size, lications. s scanned. n the module nflict with	erture pha complexit Unfortuna To isolat and the the conce	48 Nock number) sed array y and cost tely, a large e the module antenna pt of MMIC	
3a. TYPE OF REPORT Final 5. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a f element. The insertiant	FROM FROM Se if necessary n expended motivation space, at out impeda ferrite cit lon of the dule cost	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work borne and grout ance occurs when irculator is ins c circulator is because it requ	Continue on rever dance Tuning lements s , C number) C modules fo is to reduce nd based app the array i erted betwee in direct co ires the int	er 1986 r active ape e the size, lications. s scanned. n the module nflict with roduction of	d identify by t erture pha complexit Unfortuna To isolat and the the conce f circuit	48 Nock number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a	
3a. TYPE OF REPORT Final 5. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a f element. The insertiant and increases the mode separate step in the	FROM JE S S UB-GROUP Se if necessary n expended motivation space, at but impedation ferrite ci- lon of the dule cost production	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block it to develop MMI on for this work irborne and grou ance occurs when irculator is ins e circulator is because it requipe on process. Thi	Continue on rever dance Tuning lements s. number) C modules fo is to reduce nd based app the array i erted betwee in direct co ires the int s final repo	er 1986 r active ape e the size, lications. s scanned. n the module nflict with roduction of rt is a theo	d identify by the erture pha complexit Unfortuna To isolat and the the conce f circuit oretical a	48 block number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a nd experiment	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a f element. The inserti and increases the mod separate step in the evaluation of dynamic	FROM JE S UB-GROUP se if necessary n expended motivatio space, at but impeda ferrite ci lon of the dule cost productio cally tun	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work rborne and grou ance occurs when irculator is ins e circulator is because it requipe on process. Thi lng patch radiat	Continue on rever dance Tuning lements s, C number) C modules fo is to reduce nd based app the array i erted betwee in direct co ires the int s final repo ors. The re	er 1986 r active ape e the size, lications. s scanned. n the module nflict with roduction of rt is a theo sults of thi	d identify by the erture pha complexit Unfortuna To isolat and the the conce f circuit oretical a ls study s	48 block number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a nd experiment how that it i	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for change in element inp from this change, a f element. The insertiand increases the mode separate step in the evaluation of dynamic possible to change the separate	FROM JE S S UB-GROUP a expended motivation space, at ferrite cost ferrite cost lon of the dule cost production cally tuning the input	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work brorne and grou ance occurs when irculator is ins e circulator is because it requ on process. Thi Ing patch radiat	(Continue on rever dance Tuning lements s, C number) C modules fo is to reduc nd based app the array i erted betwee in direct co ires the int s final repo ors. The re icrostrip el	er 1986 r active ape e the size, lications. s scanned. n the module nflict with roduction of rt is a theo sults of thi ement over a	d identify by the erture pha complexit Unfortuna To isolat e and the the conce f circuit oretical a ls study s a wide ran	48 block number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a nd experiment how that it i ge without	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a f element. The inserti and increases the mod separate step in the evaluation of dynamic possible to change th affecting its resonant	FROM	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work broorne and grou ance occurs when irculator is ins a circulator is because it requ on process. Thi ing patch radiat impedance of a m ancy or co-planar	(Continue on rever dance Tuning lements s, C number) C modules fo is to reduc nd based app the array i erted betwee in direct co ires the int s final repo ors. The re icrostrip el pattern by	er 1986 r active ape e the size, lications. s scanned. n the module nflict with roduction of rt is a theo sults of thi ement over a moving short	d identify by the erture pha complexit Unfortuna To isolat e and the the conce f circuit oretical a is study s a wide ran t circuits	48 block number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a nd experiment how that it i ge without from one	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a f element. The inserti and increases the mod separate step in the evaluation of dynamic possible to change th	FROM JE S S UB-GROUP se if necessary n expended motivation space, at but impeda ferrite ca fout impeda ferrite ca lon of the dule cost production cally tuning the input and the frequent aving this	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block it to develop MMI on for this work irborne and grou ance occurs when irculator is ins e circulator is because it requ on process. Thi ing patch radiat impedance of a m acy or co-planar s capability may	Continue on rever dance Tuning lements s. number) C modules for is to reduce nd based app the array i erted betwee in direct co ires the int s final repo ors. The re icrostrip el pattern by alleviate t	er 1986 r active ape e the size, lications. s scanned. n the module nflict with roduction of rt is a theo sults of thi ement over a moving short he need for	d identify by the erture pha complexit Unfortuna To isolat and the the conce f circuit oretical a ls study s a wide ran t circuits the ferri	48 block number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a nd experiment how that it i ge without from one	
Ja. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 S 20 14 S 9. ABSTRACT (Continue on reverse of phased arrays for change in element ing from this change, a felement. The insertion and increases the mode separate step in the evaluation of dynamic possible to change the affecting its resonar point to another. Hat thus reducing the size 20. DISTRIBUTION / AVAILABILITY	FROM	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work Troulator is ins circulator is ins circulator is ins circulator is may because it require on process. This impedance of a may accorplanar capability may exity and cost o	(Continue on rever dance Tuning lements s, C number) C modules for is to reduce nd based app the array i erted betwee in direct co ires the int s final repo ors. The re icrostrip el pattern by alleviate t f phased arr	er 1986 er if necessary and r active ape e the size, lications. s scanned. n the module nflict with roduction of rt is a theo sults of thi ement over a moving short he need for ay antennas.	d identify by t erture pha complexit Unfortuna To isolat e and the the conce f circuit oretical a is study s a wide ran t circuits the ferri CATION	48 block number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a nd experiment how that it i ge without from one	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 20 14 9. ABSTRACT (Continue on rever Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a f element. The inserts and increases the moo separate step in the evaluation of dynamic possible to change the affecting its resonant point to another. Has thus reducing the size 20. DISTRIBUTION / AVAILABILITY EDUNCLASSIFIED/UNLIMITED	FROM S UB-GROUP Se if necessary a expended motivation space, at pout impedation ferrite citient for of the dule cost production the input in the frequent aving this ze, completion OF ABSTRACT	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block i to develop MMI on for this work borne and grout ance occurs when irculator is ins c circulator is ins because it requires because it requires because it requires because it requires because of a milling patch radiat impedance of a milling may ac capability may exity and cost o	(Continue on rever dance Tuning lements s, C number) C modules for is to reduce nd based app the array i erted betwee in direct co ires the int s final repo ors. The re icrostrip el pattern by alleviate to f phased arr	er 1986 r active ape e the size, lications. s scanned. n the module nflict with roduction of rt is a theo sults of thi ement over a moving short he need for ay antennas. ECURITY CLASSIFIE	d identify by b erture pha complexit Unfortuna To isolat e and the the conce f circuit oretical a ls study s a wide ran t circuits the ferri CATION ED	48 whock number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a nd experiment how that it i ge without from one te circulator	
3a. TYPE OF REPORT Final 6. SUPPLEMENTARY NOTATION N/A 7. COSATI CODE FIELD GROUP S 17 09 S 20 14 S 9. ABSTRACT (Continue on reven Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a fe element. The insertiand increases the mode separate step in the evaluation of dynamic possible to change the affecting its resonar point to another. Has thus reducing the siz 20. DISTRIBUTION / AVAILABILITY	FROM S UB-GROUP Se if necessary a expended motivation space, at pout impedation ferrite citient for of the dule cost production the input in the frequent aving this ze, completion OF ABSTRACT	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work Troulator is ins circulator is ins circulator is ins circulator is may because it require on process. This impedance of a may accorplanar capability may exity and cost o	(Continue on rever dance Tuning lements s, C number) C modules fo is to reduc nd based app the array i erted betwee in direct co ires the int s final repo ors. The re icrostrip el pattern by alleviate t f phased arr 21 ABSTRACT S	er 1986 er if necessary and r active ape e the size, lications. s scanned. n the module nflict with roduction of rt is a theo sults of thi ement over a moving short he need for ay antennas.	d identify by b erture pha complexit Unfortuna To isolat e and the the conce f circuit oretical a is study s a wide ran t circuits the ferri CATION 2D e) 22c OFFICE	48 block number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a nd experiment how that it i ge without from one te circulator	
Ba. TYPE OF REPORT Final S. SUPPLEMENTARY NOTATION N/A COSATI CODE FIELD GROUP S 17 09 20 14 9 ABSTRACT (Continue on reven Great effort has been radar antennas. The of phased arrays for change in element ing from this change, a f element. The inserts and increases the moo separate step in the evaluation of dynamic possible to change the affecting its resonant point to another. Has thus reducing the size 10. DISTRIBUTION / AVAILABILITY SUNCLASSIFIED/UNLIMITED	FROM	18 SUBJECT TERMS Dynamic Impe Microstrip E Phased Array and identify by block to develop MMI on for this work Troulator is ins circulator is ins circulator is ins circulator is may because it require on process. This impedance of a may accorplanar capability may exity and cost o	(Continue on rever dance Tuning lements s, C number) C modules for is to reduce nd based app the array i erted betwee in direct co ires the int s final repo ors. The re icrostrip el pattern by alleviate to f phased arr 21 ABSTRACT S 22b. TELEPHONE (617) 3 ntil exhausted.	er 1986 r active ape e the size, lications. s scanned. n the module nflict with roduction of rt is a theo sults of thi ement over a moving short he need for ay antennas. ECURITY CLASSIFIE UNCLASSIFIE (Include Area Code 77-2059	erture pha complexit Unfortuna To isolat e and the the conce f circuit oretical a is study s a wide ran t circuits the ferri CATION ED e) 22c. OFFICE RADC	48 block number) sed array y and cost tely, a large e the module antenna pt of MMIC elements as a nd experiment how that it is ge without from one te circulaton	

. The star

Contraction and the second second

UNCLASSIFIED

2022222

C. P.V. SAGARANA

17. COSATI CODES (Continued)

<u>Field</u>	Group

01 03

UNCLASSIFIED

Contents

Ł	Introduction	1
2	Theory of Loaded Microstrip Antennas	1
	2.1 Unloaded microstrip cavity	1
	2.2 Loaded microstrip cavity	
	2.2.1 Single load	4
	2.2.2 Multiple loads	7
	2.3 Input Impedance	1(
3	Application to Impedance Matching and Results	13
	3.1 Single short	14
	3.2 Two shorts	
1	Conclusions and Future Research	20
A	Additional Theoretical Results	29
	A.1 The efficient computation of the cavity Green's function	29
	A.2 Computation of the Far-Field Pattern	
	A.3 The Computation of the Energy Stored in the Cavity.	



1222

Accesio	on for			
NTIS	CRARI N			
DTIC	· • •			
Usanni				
Justific	ution.	• •		
By _				
Drut ib ition /				
Availability Codes				
Dist	Avair and for Special			
A-1				

List of Figures

1	Illustration of a typical, rectangular patch element showing dimensional parameters and co-	
	ordinate system.	2
2	The cavity model of a microstrip element.	2
3	Circuit model for the input impedance Z_{in} of a microstrip element in the vicinity of one, well	
	isolated resonant frequency.	4
4	Circuit model of a cavity loaded with a single load reactance of X_{L} .	5
5	(a) Illustration of X_r and $-X_f$ versus frequency for the three feed locations illustrated in (b).	
	(b) Rectangular patch showing three different feed locations.	6
6	Theoretical and experimental resonant frequencies of a shorted microstrip patch antenna ver-	
	sus shorting pin location.	8
7	The $(N + 1)$ -port circuit model of a loaded element driven at port 1	11
8	The circuit model for the input impedance of a loaded microstrip antenna	11
9	The locus of short-circuit locations for constant resonant frequency of the single-loaded element.	14
10	(a) Measured and computed input impedance of a single-loaded element with short-circuit at	
	(1.75, 1.04). (b) Theoretical magnetic current distribution.	15
11	(a) Measured and computed input impedance of a single-loaded element with short-circuit at	
	(2.00, 1.00). (b) Theoretical magnetic current distribution	16
12	(a) Measured and computed input impedance of a single-loaded element with short-circuit at	
	(2.25, 0.95). (b) Theoretical magnetic current distribution	17
13	(a) Measured and computed input impedance of a single-loaded element with short-circuit at	
	(2.50, 0.91) (b) Theoretical magnetic current distribution.	18
14	(a) Measured and computed input impedance of a single-loaded element with short-circuit at	
	(3.00, 0.82). (b) Theoretical magnetic current distribution	19
15	(a) Measured and computed input co-polar and cross-polar patterns in the E-plane for a	
	short-circuit at (2.50, 0.91). (b) Measured and theoretical patterns in <i>H</i> -plane	21
16	The variation of the conductance G with the <i>z</i> -coordinate of a short position taken from the	
	constant resonant frequency locus for a fixed feed at (1.00, 1.00).	22
17	(a) Measured and computed input impedance of a double-loaded element with short-circuits	
	at (2.00, 1.12) and (2.00, 2.88). (b) Theoretical magnetic current distribution.	23
18	(a) Measured and computed input impedance of a double-loaded element with short-circuits	
	at (2.50, 1.21) and (2.50, 2.79). (b) Theoretical magnetic current distribution.	24
19	(a) Measured and computed input impedance of a double-loaded element with short-circuits	
	at (3.00, 1.23) and (3.00, 2.77). (b) Theoretical magnetic current distribution.	25
20	The locus of short-circuit locations for constant resonant frequency of the double-loaded element.	26
21	(a) Measured and computed input co-polar and cross-polar patterns in the E-plane for a	
	short-circuits at (2.00, 1.12) and (2.00, 2.88). (b) Measured and theoretical patterns in H-plane.	27
22	The variation of the conductance G with the z -coordinate of a short position taken from the	
	constant resonant frequency locus for a fixed feed at (1.00, 1.00)	28
23	Formulas for $F_2(z)$ for different regions of the complex z-plane	
24	Formulas for $F_3(z)$ for different regions of the complex z-plane.	36

0.000 20 - 18

1 Introduction

During the contract period, we conducted a study of the feasibility of controlling the input impedance of a microstrip element by dynamically changing its loading. The motivation for this work is the possibility of using such elements in a scanned array. By changing the loading of the elements appropriately, one could alter the active array impedance of the elements perhaps compensating to some degree for the onset of scan blindness. While this report did not establish or refute the feasibility of the *ultimate* application, it definitely establishes the feasibility of controlling input impedance of a single element by using PIN shorting diodes.

The basic theory of loaded elements is briefly reviewed in the next section. Those features of the theory pertinent to the current application are discussed in more detail in the third section. The theoretical results and the corresponding experimental results are also presented in this section. Conclusions and suggested future research are given in the last section. Additional details of the analytical methods used can be found in Appendix A. Many of these theoretical results were just recently developed and are not presented elsewhere in the open literature. In particular, the extraction of quasistatic terms, detailed in Appendix A, makes the interactive design of these types of loaded elements feasible. This is because the determination of the resonant frequency of a loaded element is a non-linear problem requiring the iterative solution of the characteristic equation. Efficiency in computation, therefore, is critical—and the quasistatic analysis presented is highly efficient.

2 Theory of Loaded Microstrip Antennas

A brief overview of the theory of loaded microstrip antennas is presented in this section. A more detailed discussion can be found in [1].

For design purposes, one needs a simple theory which sheds light on the physical mechanisms of the microstrip antenna. Even if the theory is not the most quantitatively accurate, it is still vital to understand its physics if one is going to do creative things with the element. One theory that has proven to be physically illuminating, and relatively accurate as well, is the cavity-model analysis. It is this analysis that is used as a basis for design of loaded microstrip elements.

A typical microstrip element is illustrated in Fig. 1. The fundamental assumption made in cavity-model analysis is that the distribution of the field between the patch and the ground plane is approximately the same as that resulting in a cavity formed by closing the edge of the patch to the ground plane as illustrated in Fig. 2. The amplitude of the field distribution in the antenna and in the cavity are different. The method of determining this amplitude will be discussed later. For the purpose of determining the resonant frequency of the loaded element, the antenna will be assumed to be the same as the corresponding cavity.

2.1 Unloaded microstrip cavity

In order to analyze the loaded cavity ultimately of interest in this report, one must first understand the analysis of an unloaded cavity. Suppose one impresses a uniform, unit, vertical, filamentary electric current as illustrated in Fig. 2. The resulting cavity electric field will be vertically directed. Let the vertically directed electric field produced be denoted by $G(\tau | \tau')$, where τ is the two-dimensional position vector locating the







observation point within the cavity, and r' is the corresponding position vector locating the source current. Since this field is produced by a concentrated unit source, the field G(r|r') can be thought of as a Green's function. The boundary-value problem that this Green's function satisfies is

$$\begin{aligned} (\nabla^2 + k^2)G(\mathbf{r}|\mathbf{r}') &= j\omega\mu\delta(\mathbf{r} - \mathbf{r}'), \quad \mathbf{r} \in S \\ \nabla G(\mathbf{r}|\mathbf{r}') \cdot \hat{\mathbf{n}} &= 0, \quad \mathbf{r} \in \partial S, \end{aligned}$$

where S denotes the set of points on the patch, ∂S denotes the boundary of S, and \hat{n} is the outward-pointing unit normal on ∂S . The solution of this boundary-value problem is

$$G(\boldsymbol{r}|\boldsymbol{r}') = j\omega\mu \sum_{\boldsymbol{A}} \frac{\psi_{mn}(\boldsymbol{r})\psi_{mn}(\boldsymbol{r}')}{k^2 - k_{mn}^2},\tag{1}$$

ういたる 御たんとう かいの 御知 ひとう 大学 御子 いい

シンシンド いいま シンシンド 日 したい いいたい 一日 いいたい いたい たい

where A is the set of all pairs of non-negative integers, (m, n), and $\psi_{mn}(r)$ is the mn^{th} mode of the cavity satisfying

$$\nabla^2 \psi_{mn}(\mathbf{r}) = -k_{mn}^2 \psi_{mn}(\mathbf{r}), \quad \mathbf{r} \in S,$$
$$\nabla \psi_{mn}(\mathbf{r}) \cdot \hat{\mathbf{n}} = 0, \quad \mathbf{r} \in \partial S.$$

The series for G(r|r') diverges as $r \to r'$. This is because the inductive reactance associated with a filament is infinite. In order to obtain the input reactance of an *actual* feed, one must integrate this Green's function over the actual feed current distribution. This integration is typically a surface integral over the outer periphery of the feed structure. For the purposes of this report, it is assumed that all source and load currents are distributed uniformly on a circular cylinder of diameter d. The "location" of the source or feed is the center of the cylinder's cross section. The input impedance of the element can be found by placing the observation point at the center of the cross section of the feed, and by integrating the Green's function over the surface current. When this is done, one obtains an input reactance of

$$X_{\rm in} = X_{\rm f} + X_{\rm r},$$

where

$$X_{\mathbf{r}} = -j\omega\mu t \frac{\psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}')}{k^2 - k_{mn}^2}$$

is the resonant reactance and X_f is the feed reactance. The parameter t is the thickness of the dielectric under the patch. The pair (m, n) represents the indices of the "resonant mode." For the case of loaded microstrip elements, the resonant mode selected for determining X_r is the mode of the unloaded cavity that resonates at a frequency closest to that of the mode of interest in the loaded cavity. The feed reactance is the contribution to the total reactance from all of the non-resonant modes, principally, the higher-order modes of the element. The feed reactance is typically inductive and varies slowly with frequency. Of course, if the frequency varies too far from the resonant frequency associated with the indices (m, n), the feed reactance will contain resonant components as well. The circuit model associated with this is illustrated in Fig. 3. The resonant mode of the loaded element can be conveniently expressed in terms of the modes of the corresponding unloaded cavity as described below.



Figure 3: Circuit model for the input impedance Z_{in} of a microstrip element in the vicinity of one, well isolated resonant frequency.

2.2 Loaded microstrip cavity

The resonant frequency of a loaded cavity is that frequency at which the cavity can support a sourcefree cavity mode. At that frequency, in general, a non-sero current will flow through the multiple loads of the cavity even though no source current is applied. A non-separable loaded cavity can be converted to a separable cavity by using the equivalence principle. If the loads are removed and equivalent electric and magnetic currents are impressed on the surface bounding the now absent loads, then the field produced within the now unloaded cavity is the same as that of the original loaded cavity. It turns out that the magnetic currents called for by the equivalence principle are typically negligible [1]. The *total* electric current impressed at the location of each load is the total source-free load current that flows through the load. The unloaded cavity, in contrast to the loaded cavity is now driven by the load currents, although the load currents are, as yet, undetermined. To understand how to determine the load currents and to better understand the role played by load location, consider first an element loaded by just a single load.

2.2.1 Single load

Suppose that the load has a reactance of X_L . Then the network model of the undriven loaded cavity is that illustrated in Fig. 4. A source-free mode is desired. That is, one seeks to produce a non-sero load current with no source. This is only possible if the network is resonant. Summing the voltage around the closed loop yields the condition for resonance,

$$X_t + X_t + X_L = 0,$$

0[

$$X_t = -X_t - X_L.$$

To best interpret this characteristic equation, consider the simple and very practical case of a shortcircuit load. In this case, $X_L = 0$. Figure 5(a) contains a plot of X_r versus frequency for a rectangular



microstrip antenna for three different load locations as illustrated in Fig. 5(b). It also contains plots of the negative of the feed reactance corresponding to each feed location. The intersection of corresponding curves is the resonant frequency of the shorted microstrip element.

The resonant mode in Fig. 5 is the (0, 1) mode, the mode most commonly used in microstrip elements. For a rectangular element of dimensions $a \times b$, the normalized voltage distribution at observation point (x, y) for the (0, 1) mode is

$$v(x, y) = \cos\left(\frac{\pi y}{b}\right).$$

This is zero on the center line, y = b/2, of the patch. Such a line of zero field is called a nodal line. A point at which the voltage is stationary is called an anti-nodal point. All points on the long edges of the patch illustrated in Fig. 5 are anti-nodal points. When the load current is impressed near a nodal line, the resonant reactance curve becomes very skinny as illustrated by case 3 in Fig. 5(a). In contrast, when the load current is impressed near an anti-nodal point such as in case 1 of Fig. 5(b), then the X_r curve becomes fat. Since the voltage is stationary near an anti-nodal point, the X_r curve does not change much as one moves the load in the vicinity of the anti-nodal point. Thus the curve illustrated in case 2 of Fig. 5(a) is not much different from the case 1 curve.

This variation of the X_r curve would predict that the resonant frequency should monotonically increase as the short is moved from the nodal line to an anti-nodal point if the feed reactance were to remain constant. However, as shown in [2], the feed reactance is anything but constant with the feed position. In fact, the feed reactance increases very rapidly as the feed point approaches the edge of the patch. If the edge is an anti-node, then the X_r curve does not change much as the load is moved toward the edge, but the $-X_f$ curve is moving rapidly downward in the graph in Fig. 5 so that the resonant frequency of the shorted element decreases for loads near the edge. This makes sense because as the feed reactance increases, it becomes more like an open circuit and thus its loading effect is reduced. A typical theoretical frequency with the position variation is illustrated in Fig. 6. The actual measured variation of resonant frequency with the



location of the short agrees well with the predicted results. The location of the shorting pin is indicated by the normalized shorting pin location defined as

$$s=\frac{2}{b}\left(y'-\frac{b}{2}\right).$$

If one uses other types of load reactances, the resonant frequency of the loaded element will be modified although the effect of the feed reactance is always present. Examples of other applications of loaded microstrip elements can be found in [3], [4]. For the current application of controlling input impedance, one should *not* use just a single load. The reason why will be explained in the next section.

2.2.2 Multiple loads

For multiple loads, one cannot use the simple graphical picture presented above for predicting the behavior of a multiple-loaded element although the principles learned from this picture still apply.¹ For multiple loads, the characteristic equation is

$$\begin{vmatrix} Z_{11} + Z_{L}^{(1)} & Z_{12} & \dots & Z_{1N} \\ Z_{12} & Z_{22} + Z_{L}^{(2)} & \dots & Z_{2N} \\ \vdots & \vdots & & \vdots \\ Z_{1N} & Z_{2N} & \dots & Z_{NN} + Z_{L}^{(N)} \end{vmatrix} = 0,$$
(2)

where Z_{ij} is the z-parameter between the *i*th and *j*th port of a multiple-port microstrip cavity, and $Z_{L}^{(i)}$ is the load impedance connected to the *i*th port. The z-parameters can be computed using equation (1) as modified by integrating over the feed current distribution.² Once the resonant frequency is determined, the next step is to compute the modal field distribution of the loaded-cavity resonant mode.

To determine the field distribution of the resonant mode, one must first assume a unit (or any other non-zero current) at one of the ports and then compute the resulting currents at the remaining loads. Let Z_{\bullet} be a submatrix excluding the first row and column of the matrix in equation (2). Let $Z_{1\bullet}$ be the first column of the matrix in equation (2), excluding the first row. Let I be the column matrix of port currents excluding the current in port 1,

$$\mathbf{I} = \begin{bmatrix} I_2 \\ I_3 \\ \vdots \\ I_N \end{bmatrix}.$$

Then, if the load current in port 1 is $I_1 = 1$, the currents in the remaining ports are

$$\mathbf{I} = -\mathbf{Z}_{\mathbf{a}}^{-1}\mathbf{Z}_{\mathbf{1a}}.$$

15 ちょうよう ちょうだい

¹Actually, one could, in principle, apply the graphical analysis sequentially. That is, first find the effect of a single load. Then create a new graph in which X_t is the resonant reactance and X_f is the feed reactance of the singly-loaded patch. From these, the resonant frequency of the doubly-loaded element could be constructed.

² There is more to the computation than what has been outlined here. A very efficient analysis has been devised for computing the *z*-parameters in which the series is highly accelerated. The details of this are included in Appendix A.



The resulting field distribution is

$$\Psi(\mathbf{r}) = j\omega\mu \sum_{A} \sum_{\ell=1}^{N} I_{\ell} \frac{\psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}_{\ell})}{k^2 - k_{mn}^2},$$
(3)

where $\psi_{mn}(r)$ and k_{mn} are the modal fields and corresponding resonant wavenumbers in the unloaded cavity. Strictly speaking, this expression is only valid for observation points r outside of the load regions. That is, if the diameter of the *i*th load is d_i , then $|r - r_i|$ must be larger than $d_i/2$.

The input impedance of the loaded element is computed by analyzing the cavity with the actual dielectric replaced with an artificially lossy dielectric—one whose losses account for the radiative and ohmic losses of the original microstrip antenna. The effective loss tangent of this dielectric is $\delta_{\text{eff}} = 1/Q$ where Q is the quality factor of the antenna. It is given by

$$Q = \left(\frac{1}{Q_{\rm rad}} + \frac{1}{Q_{\rm sw}} + \frac{1}{Q_{\rm m}} + \frac{1}{Q_{\rm d}}\right)^{-1},$$

where Q_{rad} is the radiative quality factor, Q_{sw} is the quality factor associated with the surface wave, Q_m is the quality factor associated with metal heating loss, and Q_d is the dielectric quality factor. These are given by

$$Q_{\rm red} = \frac{2\omega W_E}{P_{\rm red}}$$
$$Q_{\rm sw} = \frac{2\omega W_E}{P_{\rm sw}},$$
$$Q_{\rm m} = \frac{t}{\Delta},$$
$$Q_{\rm d} = \frac{1}{\delta},$$

where P_{rad} is the time-averaged power radiated by the antenna, P_{sw} is the time-averaged power carried away by the surface wave, Δ is the skin depth in the metal cladding, δ is the loss tangent in the actual dielectric, and W_E is the average energy stored in the electric field at the resonant frequency of the cavity

The parameters in the expressions for the quality factors would appear to depend on the field under the patch. Actually, the quality factors depend only on the *distribution* of the mode for which the quality factors are being computed. The field could be multiplied by any arbitrary constant without affecting the quality factor. At the resonant frequency of the $\Psi(r)$ of the loaded element, the field is strongly dominated by $\Psi(r)$ itself. Thus, one can obtain an approximation for the quality factors by assuming the field distribution below the patch is $\Psi(r)$, with the contributions of the other non-resonant modes of the loaded patch ignored.

The radiated field can be computed under the following approximation. The ground plane and the dielectric are ignored, and a magnetic current filament is impressed in the presence of the ground plane. The magnetic current flows around the edge of the patch and is equal to the voltage between the patch and the ground plane. The surface wave can be determined by allowing this same magnetic current filament to

act in the presence of a grounded dielectric slab, although for sufficiently thin elements, the power carried in the surface wave is negligible. The magnetic current is actually sampled at discrete points and linearly interpolated between the sample points.³ The radiated field is computed analytically and the associated radiated power is determined by numerical quadrature.

The electric stored energy is computed by integrating the square of the electric field. That is,

$$W_E = \frac{1}{2} t \epsilon \iint_{S} |E|^2 dS \approx \frac{1}{2} t \epsilon \iint_{S} |\Psi(\mathbf{r})|^2 dS.$$
(4)

The singularities at the load locations in equation (3) are logarithmic; their squares are integrable. As a result, equation (3) can be used for t|E| with little error. Since the modes of the unloaded cavity are orthonormal, the double integration above reduces to⁴

$$\omega W_E = \frac{1}{2} t \epsilon_r \mu_r^2 k_0^3 \eta_0 \sum_{\ell=0}^N \sum_{i=0}^N I_\ell I_i \sum_A \frac{\psi_{mn}(r_i) \psi_{mn}(r_\ell)}{(k^2 - k_{mn}^2)^2}.$$

Once the quality factor of the loaded element is determined, then its input impedance can be computed.

2.3 Input Impedance

Assume that one more port is added to the antenna, the $(N+1)^{st}$ port. The circuit model as seen from the $(N+1)^{st}$ port for the loaded cavity is illustrated in Fig. 7. The circuit model of the antenna is shown in Fig. 8. The input admittance of the lossy tank circuit only is

$$Y_{\rm r} = G\left[1+jQ\left(\left(\frac{\omega}{\omega_0}\right)^2-1\right)\right]$$
$$\approx G\left[1+j2Q\left(\frac{\omega}{\omega_0}-1\right)\right],$$

where Q is the quality factor of the lossy tank, and ω_0 is the resonant angular speed of the lossy tank. These are given by

$$Q = \frac{R}{\omega_0 L} = \frac{2\omega W_E}{P}$$
$$\omega_0^2 = \frac{1}{LC},$$

where P is the power dissipated in the resistor, and W_E is the time-averaged energy stored in the capacitor. The power P is related to the conductance G and the voltage V_t across the tank circuit by

$$|V_t|^2 G = P. \tag{5}$$

The circuit quantities are related to the antenna by choosing Q to be the antenna quality factor, and P to be the power radiated by the loaded-element resonant mode given by equation (3). The voltage V_t is

³See Appendix A for details of this computation.

⁴ The series for W_E can also be accelerated, the details of which are given in Appendix A.





where τ_f is the center of the feed for the loaded element—the location of the $(N+1)^{st}$ port. Note that V_t is not the feed voltage V_f since the former *does not* include the effect of the feed reactance. The conductance G can thus be computed from equation (5).

The feed reactance, X_f , can be modeled as a linear process over the band of operation. Let the reactance corresponding to the lossless loaded cavity (R = 0) be denoted by X_r . Let the total reactance be X(f). Let

$$X_{\rm f} = X_{\rm f0} + (f - f_0) X_{\rm f1},$$

where f_0 corresponds to ω_0 . Finally, let

$$f_{+} = \left(1 + \frac{1}{2Q}\right) f_{0},$$
$$f_{-} = \left(1 - \frac{1}{2Q}\right) f_{0}.$$

The resonant component of the reactance can be written as

$$X_{\rm r} = \frac{2\pi L(f_0 + \Delta f)}{1 - (1 + \Delta f/f_0)^2},$$

where $\Delta f = f - f_0$. For small Δf , this can be written approximately as

$$X_{\rm r}\approx -\pi L \frac{f_0^2}{\Delta f} - \pi L \frac{f_0}{2}.$$

Then,

$$X_{\rm fo} \approx \frac{1}{2}(X(f_+) + X(f_-)) + \frac{\omega_0 L}{4}.$$

Similarly,

$$X_{\mathrm{fl}} \approx \frac{Q}{f_0} \left[X(f_+) - X(f_-) + 2Q\omega_0 L \right].$$

The quantity $\omega_0 L = R/Q$ so that

$$X_{\rm f0} \approx \frac{1}{2}(X(f_+) + X(f_-)) + \frac{R}{4Q},$$

and

$$X_{f1} \approx \frac{Q}{f_0} [X(f_+) - X(f_-) + 2R].$$

What remains is to determine the input reactance of the ideal cavity at the upper and lower frequencies f_+ and f_- .

Let the indices of the loaded ports be numbered from 1 to N with corresponding port voltages and currents of V_1 , V_2 , ..., V_N and I_1 , I_2 , ..., I_N . The $(N + 1)^{\text{st}}$ port is the feed port with feed current of $I_f = 1$ and feed voltage $V_f = Z_{\text{in}}$ where Z_{in} is the input impedance of the loaded element. If

$$\mathbf{V} = \begin{bmatrix} V_1 \\ V_2 \\ \vdots \\ V_N \end{bmatrix}$$

and I is redefined as

$$\mathbf{I} = \begin{bmatrix} I_1 \\ I_2 \\ \vdots \\ I_N \end{bmatrix}$$

then,

$$\mathbf{V} = \mathbf{Z}\mathbf{I} + \mathbf{Z}_{mf}I_{f},$$
$$V_{f} = \mathbf{Z}_{mf}^{t}\mathbf{I} + Z_{ff}.$$

The impedance matrix Z contains the multiport impedances between the *loaded* ports. The $(1 \times N)$ -matrix Z_{mf} contains the mutual impedances between the feed port τ_f and the load ports τ_m . The self-impedance of the feed port in the unloaded cavity is Z_{ff} . Let the diagonal load impedance matrix be

$$\mathbf{Z}_{L} = \text{Diag}\left[Z_{L}^{(1)}, Z_{L}^{(2)}, \ldots, Z_{L}^{(N)}\right].$$

Then

$$V = -Z_{L}I,$$

$$I = -(Z + Z_{L})^{-1}Z_{mf}, \text{ and}$$

$$jX(f) = V_{f} = Z_{ff} - Z_{mf}^{t}(Z + Z_{L})^{-1}Z_{mf}$$

Having thus computed X(f), one can now evaluate the input impedance Z_{in} of the antenna using

$$Z_{\rm in} \approx X_{\rm f0} + X_{\rm f1}(f-f_0) + \frac{1}{G[1+j2Q(f/f_0-1)]}$$

As the results of the next section demonstrate, this expression is reasonably accurate over the band of a single resonant mode of the loaded element.

3 Application to Impedance Matching and Results

In this section, those elements of the theory presented in the previous sections specific to the application of varying impedance are presented together with corroborating experimental results. The objective in this application is to vary the input impedance while keeping the resonant frequency and pattern of the element fixed. This objective can be met by placing short-circuits at one or more appropriately chosen locations on the patch. These short-circuits can be PIN diodes thus allowing adaptation of the element to changing conditions such as the scan angle in a phased array. The theory and results given below assume that the loads are short circuits. One could probably also use voltage-controlled capacitors, varactor diodes. Use of varactors would probably simplify the biasing of the diodes. This possibility is currently under study.



As seen in the previous section, one can vary the frequency by varying the location of a short circuiting pin. It is possible to vary the input impedance with a single short without altering the resonant frequency. The way that the input impedance is varied for a *fixed* feed location is to move the *nodal line* of the loaded resonant mode by moving the shorting pin location. The closer the nodal line is moved to the feed, the lower the peak input resistance will be. The trick is to move the shorting pin in such a way that at least the resonant frequency is unchanged. This was done using an interactive computer program with graphical output based on the theory discussed in the previous section.

3.1 Single short

The results of our computer program indicated that if a single short-circuit were placed on the locus illustrated in Fig. 9, then the resonant frequency of the resulting loaded elements should be identical. Using just a single short, one can vary the input impedance as is illustrated in Figs. 10-14. These figures contain the computed magnetic current distribution, the computed input impedance, and the measured input impedance of the loaded elements. In all cases, the patch dimensions were 4.00 cm wide by 6.00 cm long by 0.158 cm thick. The dielectric substrate was 3M Corporation's CuClad 250 glass reinforced, double clad PTFE. The manufacturer-supplied nominal dielectric constant was 2.43. The feed point was always at (1.00, 1.00), where the coordinates represent the distance in cm from a reference corner of the patch. The input impedance was collected using a computer-controlled, Hewlett-Packard 8410 network analyzer at the University of Houston.

It is quite clear from Figs. 10-14 that the magnetic current distributions around the edge of the patch are asymmetrical. The pattern that results from such a distribution will have a significant cross-polarized pattern







مستنع جلاحدددت



Record and



21 E. LANDONS M. ROUDDARD, KAAAAAM, KAAAAA MAAAAA



だんがい



Bacharacter

22.2







although the E-plane pattern will be typical of the (0, 1)-mode of a rectangular element. The theoretical and experimentally determined patterns for a patch loaded with a single short at (2.50, 0.91) are illustrated in Fig. 15. The measured patterns were taken with the element mounted on a 1.05m (8.7-wavelength) circular ground plane. The element was driven at a frequency of 2470 MHz. Our pattern range is fairly new: it is difficult to say how much of the cross-polarization is due to errors introduced by the range and how much is due to the asymmetry in the element's magnetic current distribution. Nevertheless, the cross-polarized patterns appear to be at least qualitatively consistent with the predicted patterns. Note that some of the discrepancy, especially the scalloping of the pattern and the loss of gain at the horizon is due to the finite size of the ground plane.

In any case, it is clear that the cross-polarization arising when a single short circuit is used is significant and probably unacceptable in many applications. Because of this, at least two shorts should be used in symmetrical locations. There is another reason why two or more shorts should be used. It is clear from the measured and computed input impedances that the impedance range obtained is not extremely broad for a single-loaded element. We did not measure impedance levels for shorts any closer to the feed than those illustrated in Figs. 10-14 because of the obstruction caused by mounting an SMA feed. However we have plotted the theoretical resistance R versus x, where x is the x-coordinate of a single short-circuit placed along the locus illustrated in Fig. 9. This plot is contained in Fig. 16. This result should be compared with the results for the double-loaded elements considered next.

3.2 Two shorts

With two shorts located symmetrically with respect to the long center line of the patch one can eliminate the cross-polarization in the H-plane. Furthermore, one can more easily obtain a wider variation of input impedance. Figures 17-19 contain the theoretical magnetic current distribution, and the measured and computed input impedances of elements loaded by symmetrically located pairs of short-circuits. The locus of points on which these pairs of short-circuits should lie is illustrated in Fig. 20.

The theoretical and measured patterns are given in Fig. 21. The measured cross-polarization is disappointingly high in this case. As mentioned before, this may be due to errors introduced by the range. Nevertheless, the cross-polarization is definitely reduced from what it was in the case of the single-loaded element.

Finally, it is clear from Figs. 17-19 and Fig. 22 that the impedance variation is greater for the doubleloaded element than for the single-loaded element. In short, it appears that the performance yielded by a single short falls short of that obtainable using two shorts.

4 Conclusions and Future Research

There are several conclusions that can be drawn from the theory and results presented in this report.

1. It is possible to change the input impedance of a microstrip element over a wide range without affecting its resonant frequency or co-polar pattern by moving short-circuits from one point to another.



ددددد









j





and the second many of the second statement of the second s



- 2. The theory that predicts this result has been corroborated by experiment. Specifically, the experiment shows that the resonant frequency of the mode is left relatively unchanged by the appropriate placement of short-circuits. Small deviations between the predicted and observed resonant frequency do exist. They are due partly to errors in fabrication of the element and partly due to the errors introduced by the cavity model upon which the theory is based. The experiment also shows that the agreement between the predicted and observed input impedance is excellent in most cases. Finally, there was qualitative agreement between theoretical patterns and measured patterns although the measured cross-polarized components in the double-loaded element were much higher than expected from the theory—possibly a problem with our range and ground plane fixture.
- 3. From the point of view of producing lower cross-polarization and from the point of view of more easily varying the impedance level over a wide range, two short-circuits are better than one short-circuit. Each short-circuit pair should be biased together with the same biasing voltage.

Some important items are left for future research. These include the following.

- 1. A simulation of loaded elements in a phased array needs to be carried out to determine the basic feasibility of the ultimate application. This, we propose, as the major deliverable of a future research contract.
- 2. Because each diode or diode pair needs a biasing line, the number of biasing lines could become quite large if many levels of adjustment in impedance are provided. For this reason, we are currently studying the feasibility of using voltage-controlled capacitors to change the impedance level.







Figure 22: The variation of the conductance G with the z-coordinate of a short position taken from the constant resonant freugency locus for a fixed feed at (1.00, 1.00).
A Additional Theoretical Results

This appendix contains additional theoretical results that are implemented in the computer program used to generate the data presented in Section 3. There are three topics within this appendix:

ZZZZZZE PRZZZZZ (* 1993–1992)

- 1. The efficient computation of the cavity Green's function,
- 2. The computation of the far-field pattern, and
- 3. The computation of the energy stored in the cavity.

A.1 The efficient computation of the cavity Green's function

The expression for the Green's function in equation (1) is very slowly converging and not particularly useful, especially for patches of other than rectangular shape. It can be accelerated in the following way. First partition the set A of mode indices into the union of three sets,

$$A = \{(0,0)\} \cup \overline{A}_{\xi} \cup A_{\xi}.$$

The first set, consisting of a single element, represents the indices of the "D.C. mode." This is the mode of the unloaded cavity that resonates at zero frequency—it is just a constant. Since the modes are assumed to be normalized, this constant is

$$\psi_{00}(\boldsymbol{r}) = \frac{1}{\sqrt{S}}$$

where S represents the area of the patch.⁵ The third set is the set of modes whose resonant wavenumbers are greater than or equal to ξk_{max} :

$$A_{\xi} = \{(m, n) | k_{mn} \geq \xi k_{\max} \}.$$

The parameter k_{max} is the

$$k_{\max} = \frac{2\pi f_{\max} \sqrt{\epsilon_r \mu_r}}{c},$$

where c is the speed of light in a vacuum, and f_{\max} is the maximum frequency of interest for the antenna—a number that can be specified a priori for any analysis. The parameter ξ is some real constant greater than one. The second set is the complement of A_{ξ} with respect to the set A_{0} ,

$$\overline{A}_{\xi} = A_0 - A_{\xi},$$

where

$$A_0 = A - \{(0,0)\}$$

is the set of all mode index pairs except for that corresponding to the D.C. mode.

Suppose that $|\zeta| \leq 1/\xi$. Then one can approximate the fraction $1/(1-\zeta^2)$ by

⁵The same symbol is used to represent the set of points making up the patch. No confusion between the two uses should arise.

$$\frac{1}{1-\zeta^2} \approx a_0 + a_1\zeta^2 + a_2\zeta^4 + \cdots + a_{L-1}\zeta^{2(L-1)}.$$

Then for mode indices in A_{ξ} , one can approximate the fraction $1/(k^2 - k_{mn}^2)$ by

$$\frac{1}{k^2 - k_{mn}^2} \approx -a_0 \frac{1}{k_{mn}^2} - a_1 \frac{k^2}{k_{mn}^4} - \cdots - a_{L-1} \frac{k^{2L-2}}{k_{mn}^{2L}}.$$

Thus, the sum in equation (1) can be partitioned and approximated as

$$G(\mathbf{r}|\mathbf{r}') \approx j\omega\mu \left\{ \frac{1}{S} + \sum_{\overline{A}_{\ell}} \frac{\psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}')}{k^2 - k_{mn}^2} - a_0 \sum_{A_{\ell}} \frac{\psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}')}{k_{mn}^2} - a_1 k^2 \sum_{A_{\ell}} \frac{\psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}')}{k_{mn}^4} - \dots - a_{L-1} k^{2L-2} \sum_{A_{\ell}} \frac{\psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}')}{k_{mn}^2} \right\}.$$

This sum can be recast in a more convenient form for acceleration by summing over A_0 instead of A_{ξ} . The result is

$$G(\mathbf{r}|\mathbf{r}') \approx j\omega\mu \left\{ \frac{1}{S} + \sum_{\overline{A}_{\ell}} \left[\frac{1}{k^2 - k_{mn}^2} + a_0 \frac{1}{k_{mn}^2} + a_1 \frac{k^2}{k_{mn}^4} + \dots + a_{L-1} \frac{k^{2L-2}}{k_{mn}^{2L}} \right] \psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}') - a_0 \sum_{A_0} \frac{\psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}')}{k_{mn}^2} - a_1 k^2 \sum_{A_0} \frac{\psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}')}{k_{mn}^4} - \dots - a_{L-1} k^{2L-2} \sum_{A_0} \frac{\psi_{mn}(\mathbf{r})\psi_{mn}(\mathbf{r}')}{k_{mn}^{2L}} \right\}.$$

There are compromises to be made in the choice of the parameter ξ . If ξ is chosen too near 1, then the required number of terms L necessary to approximate the fraction $1/(1-\zeta^2)$ becomes very large. On the other hand, if ξ is chosen to be much greater than 1, L may be small, but the number of elements in the set \overline{A}_{ξ} becomes very large. Either of these conditions is undesirable. A reasonable choice of ξ is $\xi = 2$. If L is then chosen to be 2, and the coefficients a_0 and a_1 are chosen to be 0.989 and 1.331, respectively, the error in the approximation is about one percent. Thus, the Green's function can be approximated as

$$G(\mathbf{r}|\mathbf{r}') = j\omega\mu \left\{ \frac{1}{S} + \sum_{\overline{A}_{\ell}} \left[\frac{1}{k^2 - k_{mn}^2} + a_0 \frac{1}{k_{mn}^2} + a_1 \frac{k^2}{k_{mn}^4} \right] \psi_{mn}(\mathbf{r}) \psi_{mn}(\mathbf{r}') + a_0 G_0(\mathbf{r}|\mathbf{r}') + k^2 a_1 G_1(\mathbf{r}|\mathbf{r}') \right\},$$
(6)

where

$$G_0(\boldsymbol{r}|\boldsymbol{r}') = -\sum_{\boldsymbol{A}_0} \frac{\psi_{mn}(\boldsymbol{r})\psi_{mn}(\boldsymbol{r}')}{k_{mn}^2},$$

$$G_1(\boldsymbol{r}|\boldsymbol{r}') = -\sum_{\boldsymbol{A}_0} \frac{\psi_{mn}(\boldsymbol{r})\psi_{mn}(\boldsymbol{r}')}{k_{mn}^4}.$$

The decomposition of the Green's function expressed in equation (6) represents an expansion of G in terms of its first few lowest-order modes plus the contribution due to all higher-order modes, a quasistatic expansion. Once the quasistatic terms $G_0(r|r')$ and $G_1(r|r')$ are computed, then the Green's function can be evaluated very efficiently for different frequencies—the most difficult part will have been done once and for all for a given pair of source and observation points r and r'.

The series for $G_0(r|r')$ and $G_1(r|r')$ are still very slowly converging, as slowly converging as the series for G. These quasistatic Green's functions satisfy the boundary-value problem,

$$\nabla^2 G_0(\boldsymbol{r}|\boldsymbol{r}') = \delta(\boldsymbol{r} - \boldsymbol{r}') - \frac{1}{S}, \quad \boldsymbol{r} \in S,$$

$$\nabla G_0(\boldsymbol{r}|\boldsymbol{r}') \cdot \hat{\boldsymbol{n}} = 0, \quad \boldsymbol{r} \in \partial S;$$

$$\nabla^2 G_1(\boldsymbol{r}|\boldsymbol{r}') = -G_0(\boldsymbol{r}|\boldsymbol{r}'), \quad \boldsymbol{r} \in S,$$

$$\nabla G_1(\boldsymbol{r}|\boldsymbol{r}') \cdot \hat{\boldsymbol{n}} = 0, \quad \boldsymbol{r} \in \partial S.$$

http://downloading.

One can obtain G_0 and G_1 by evaluating

$$G_{0} = \frac{1}{j\omega\mu} \lim_{k \to 0} \left(G - \frac{j\omega\mu}{k^{2}S} \right),$$

$$G_{1} = \frac{1}{j\omega\mu} \lim_{k \to 0} \left\{ \frac{\partial}{\partial k^{2}} \left(G - \frac{j\omega\mu}{k^{2}S} \right) \right\}.$$
(8)

By expanding G in a Laurant series in k^2 about $k^2 = 0$, one can evaluate these limits. To this end, the patch is first described in terms of a coordinated system appropriate to the patch shape.

Let u and v be the coordinate variables of an orthogonal coordinate system derived through a conformal mapping of the rectangular coordinate system. This mapping is chosen so that it maps the patch into a rectangular patch in the (u, v)-plane. Of course, if the patch is already rectangular, then u = x, v = y. For a circular patch, a circular sector patch, an annular patch, or an annular sector patch, the transformation used is

$$x = ae^v \cos u$$

 $y = ae^v \sin u$,

where a is the outer radius of the patch. The transformation need not be analytic, but it must satisfy

$$\begin{vmatrix} \frac{\partial u}{\partial x} \\ \frac{\partial v}{\partial x} \end{vmatrix} = \begin{vmatrix} \frac{\partial v}{\partial y} \\ \frac{\partial v}{\partial x} \end{vmatrix},$$

If these equations are satisfied, then the boundary value problem for G is transformed into

$$[\nabla^2 + k^2 h(u,v)^2] G(\boldsymbol{r}|\boldsymbol{r}') = j\omega\mu\delta(\boldsymbol{r}-\boldsymbol{r}'),$$

where h(u, v) is the common scale factor of the u and v variables. If the patch is separable, then

$$h(u,v)^2 = f(u) + g(v).$$

In this case, G can be expressed as

$$G(\mathbf{r}|\mathbf{r}') = j\omega\mu \sum_{m=0}^{\infty} \frac{U_m(u)U_m(u')V_m^-(v_<)V_m^+(v_>)}{N_m W\left(V_m^-, V_m^+\right)},\tag{9}$$

where

$$N_{m} = \int_{u_{-}}^{u_{+}} U_{m}(u)^{2} du,$$

$$W\left(V_{m}^{-}, V_{m}^{+}\right) = W_{m} = V_{m}^{-}(v_{+})V_{m}^{+\prime}(v_{+}) - V_{m}^{-\prime}(v_{+})V_{m}^{+}(v_{+}),$$

$$v_{<} = \begin{cases} v, & v < v' \\ v', & v' < v \end{cases},$$

$$v_{>} = \begin{cases} v, & v' < v \\ v', & v < v' \end{cases}.$$

The prime "'" on dependent variables indicates differentiation with respect to argument. The primes on u and v indicate the source point location (u', v') in the (u, v)-coordinate system. The U_m 's and V_m 's satisfy the separated Helmholtz equations,

$$U_m'' + (\alpha_m^2 + k^2 f(u)) U_m = 0,$$

$$V_m'' + (-\alpha_m^2 + k^2 g(v)) V_m = 0,$$

where the "±" superscript has been suppressed on the "V" for convenience.

The α_m^2 is the separation constant determined by applying the pair of homogeneous boundary conditions that $U_m(u)$ satisfies at $u = u_{\pm}$, where u_{-} is the left boundary of the transformed patch and u_{+} is its right boundary. Similarly, v_{-} is the lower boundary of the transformed patch and v_{+} is its upper boundary. These boundary conditions depend on the geometry of the patch. They are either the physical boundary condition that the derivative $U_m(u)$ must vanish at one or both of the limits of u, or that $U_m(u)$ must satisfy conditions that will make the field and its derivatives continuous at the limits of u. Without loss of generality, one can always assume that $V_m^{+\prime}(v_{+}) = 0$. The condition that $V_m^{-}(v)$ satisfies can also be the physical boundary condition that its derivative vanishes at $v = v_{-}$, or that the field be continuous at $v = v_{-}$. These parameters can be expanded in a power series in k^2 as

$$U_m = U_{0m} + k^2 U_{1m} + k^4 U_{2m} + \cdots,$$

$$V_{m} = V_{0m} + k^{2}V_{1m} + k^{4}V_{2m} + \cdots,$$

$$\alpha_{m}^{2} = \alpha_{0m}^{2} + k^{2}\alpha_{1m}^{2} + k^{4}\alpha_{2m}^{2} + \cdots,$$

$$N_{m} = N_{0m} + k^{2}N_{1m} + k^{4}N_{2m} + \cdots,$$

$$W_{m} = W_{0m} + k^{2}W_{1m} + k^{4}W_{2m} + \cdots.$$

The U_{nm} 's and the V_{nm}^{\pm} 's satisfy the sequence of differential equations,

$$U_{nm}'' + \alpha_{0m}^2 U_{nm} = -\sum_{\ell=0}^{n-1} \alpha_{(n-\ell),m}^2 U_{\ell m} - f(u) U_{(n-1),m},$$

$$V_{nm}'' - \alpha_{0m}^2 V_{nm} = \sum_{\ell=0}^{n-1} \alpha_{(n-\ell),m}^2 V_{\ell m} - g(v) V_{(n-1),m},$$

where again the superscript " \pm " on the V's has been dropped for convenience. In addition to applying the boundary conditions discussed above, the following conditions are also applied to obtain the solution in the most convenient form:

またい ひん マイン・ション・シート

مسكر إندالك فالكرد فريد

1

A MARKAR MINA CONTRACTOR AND A MARKAR A

ł

$$N_{1m} = N_{2m} = \dots = 0,$$

$$V_{nm}^{+}(v_{+}) = 0, \quad n > 0,$$

$$V_{0m}^{+}(v_{+}) = 1,$$

$$V_{nm}^{-}(v_{-}) = 0, \quad n > 0,$$

$$V_{0m}^{-}(v_{-}) = 1.$$

These conditions can be applied since any of the multiplication of the U and V functions by any arbitrary function of k^2 leaves G(r|r') unchanged, but *does change* the coefficients of the series in k^2 listed above i.e., the expansions given above are *not* unique. This choice simplifies the coefficients of the expansion of the Wronskian; they become

$$W_{nm} = -V_{nm}^{-\prime}(v_+).$$

Using the solutions of these equations in equations (7), (8), and (9) yields the expressions

$$G_{\ell}(\boldsymbol{r}|\boldsymbol{r}')=\boldsymbol{r}_{\ell 0}+\sum_{m=0}^{\infty}\boldsymbol{r}_{lm}.$$

The r's are

$$r_{00} = \frac{1}{S} \left\{ n_{10} - \frac{\Delta u}{S} W_{20} \right\},$$

$$r_{10} = \frac{1}{S} \left\{ n_{20} - n_{10} \frac{\Delta u}{S} W_{20} - \frac{\Delta u}{S} W_{30} + \left(\frac{\Delta u}{S} W_{20} \right)^2 \right\},$$

$$r_{0m} = \frac{2n_{0m}}{\Delta u W_{0m}}, \qquad m > 0,$$

$$r_{1m} = \left\{ n_{1m} - \frac{n_{0m} W_{1m}}{W_{0m}} \right\} \frac{2}{\Delta u W_{0m}}, \qquad m > 0,$$

where $\Delta u = u_+ - u_-$. The n's are given by

$$\begin{split} n_{0m} &= U_{0m}(u)U_{0m}(u')V_{0m}^{-}(v_{<})V_{0m}^{+}(v_{>}), \\ n_{1m} &= U_{1m}(u)U_{0m}(u')V_{0m}^{-}(v_{<})V_{0m}^{+}(v_{>}) + U_{0m}(u)U_{1m}(u')V_{0m}^{-}(v_{<})V_{0m}^{+}(v_{>}) \\ &+ U_{0m}(u)U_{0m}(u')V_{1m}^{-}(v_{<})V_{0m}^{+}(v_{>}) + U_{0m}(u)U_{0m}(u')V_{0m}^{-}(v_{<})V_{1m}^{+}(v_{>}), \\ n_{20} &= U_{20}(u) + U_{20}(u') + V_{20}^{-}(v_{<}) + V_{20}^{+}(v_{>}) \\ &+ U_{10}(u)U_{10}(u') + V_{10}^{-}(v_{<})V_{10}^{+}(v_{>}) + U_{10}(u')V_{10}^{-}(v_{<}) + U_{10}(u')V_{10}^{+}(v_{>}). \end{split}$$

The summand of G_0 always contains the term

$$\frac{j\omega\mu}{2\pi}\Re\left\{\frac{1}{m}e^{-m\nu z}\right\},\,$$

where $\alpha_{0m} = m\nu$, $z = v_{>} - v_{<} + j(u - u')$. This term can be summed in closed form to yield

$$G_0(\boldsymbol{r}|\boldsymbol{r}') = \frac{j\omega\mu}{2\pi} \left\{ \nu \frac{v_2 - v_2}{2} - \ln|\nu z| - \ln\left|\frac{\sinh(\nu z/2)}{\nu z/2}\right| \right\} + \text{remainder terms.}$$

For source points (u', v') not on the edge of the patch, the remainder terms of G_0 in the preceeding expression are non-singular as $(u, v) \rightarrow (u', v')$ The logarithmic singularity of the Green's function is explicitly extracted by this method. The remainder terms of G_0 and of G_1 involve sums over m of terms of the form

$$\frac{e^{-m\nu_2}}{(m\nu)^\ell}$$

where z_i is a complex number whose real and imaginary parts are linear functions of u, u', v, and v', and $\ell = 1, 2, 3, \ldots$

The series associated with these terms can be evaluated efficiently using the functions

$$F_n(z) = \Re\left\{\sum_{\ell=1}^{\infty} \frac{e^{-\ell z}}{\ell^n}\right\}, \quad \ell = 1, 2, \ldots, \quad \Re\{z\} \ge 0.$$

The first function $F_1(z)$ can be summed in terms of elementary functions and is given by

$$F_1(z) = \frac{\Re\{z\}}{2} - \ln\{2|\sinh(z/2)|\}$$

The second and third functions $F_2(z)$ and $F_3(z)$ can be computed for z in various regions of the complex z-plane as indicated in Figs. 23-24. The formulas are extended by the following identities to regions of the complex z-plane not covered in these two figures:





ないたいのは、「「ないいい」という。

 $F_n(z) = F_n(z \mod 2\pi),$ $F_n(z) = F_n(z^*).$

きたいいい いちょう いいい いいい

This method has been used to obtain explicit formulas for the several differently shaped patches. The formulas for rectangular patches are

$$z_{0} = \frac{\pi}{a} [(y_{>} - y_{<}) + j(x - x')],$$

$$z_{1} = \frac{\pi}{a} [(y_{>} + y_{<}) + j(x - x')],$$

$$z_{2} = \frac{\pi}{a} \{[2b - (y_{>} + y_{<})] + j(x - x')\},$$

$$z_{3} = \frac{\pi}{a} [(y_{>} - y_{<}) + j(x + x')],$$

$$z_{4} = \frac{\pi}{a} [(y_{>} + y_{<}) + j(x + x')],$$

$$z_{5} = \frac{\pi}{a} \{[2b - (y_{>} + y_{<})] + j(x + x')\},$$

$$r_{00} = \frac{1}{2S} \left\{ \frac{b^{2}}{3} - [y_{<}^{2} + (b - y_{>})^{2}] \right\},$$

$$r_{10} = \frac{1}{4S} \left\{ \frac{1}{6} [y_{<}^{2} + (b - y_{>})^{2}] + y_{<}^{2} (b - y_{>})^{2} - \frac{1}{3} b^{2} [y_{<}^{2} + (b - y_{>})^{2}] + \frac{7}{90} b^{2} \right\},$$

$$\sigma_{\ell} = -\Re\{z_{\ell}\}, \quad \ell = 0, 1, 2,$$

$$\sigma_{4} = -\frac{\pi}{a} [2b - (y_{>} - y_{<})],$$

$$\Omega_{0m}(y|y') = \frac{\sum_{\ell=0}^{3} e^{m\sigma_{\ell}}}{1 - e^{-2m\pi b/a}},$$

$$\Omega_{1m}(y|y') = \frac{\sum_{\ell=0}^{3} (b\pi/a + \sigma_{\ell})e^{m\sigma_{\ell}}}{1 - e^{-2m\pi b/a}},$$

$$\Omega_{2m}(y|y') = \left[\frac{1}{m} + \frac{b\pi}{a} \coth(m\pi b/a)\right] \Omega_{0m}(y|y') - \Omega_{1m}(y|y'),$$

$$H_1(z) = \begin{cases} F_1(z), & |z| \geq \frac{\pi d}{2a}; \\ F_1\left(\frac{\pi d}{2a}\right), & |z| < \frac{\pi d}{2a}, \end{cases}$$

$$G_0(r|r') = r_{00} - \frac{1}{\pi} \left\{ \sum_{m=1}^{\infty} \frac{1}{m} \left[\Omega_{0m}(y|y') - \sum_{\ell=0}^{2} e^{m\sigma_{\ell}} \right] \cos\left(\frac{m\pi x}{a}\right) \cos\left(\frac{m\pi x'}{a}\right) - \frac{1}{2} \sum_{\ell=0}^{5} H_1(z_{\ell}) \right\},$$

$$G_{1}(\boldsymbol{r}|\boldsymbol{r}') = r_{10} - \frac{a^{2}}{2\pi^{3}} \left\{ \sum_{m=1}^{\infty} \frac{1}{m^{2}} \left[\Omega_{2m}(\boldsymbol{y}|\boldsymbol{y}') - \sum_{\ell=0}^{2} \left(\frac{1}{m} - \sigma_{\ell} \right) e^{m\sigma_{\ell}} \right] \cos\left(\frac{m\pi \boldsymbol{x}}{a} \right) \cos\left(\frac{m\pi \boldsymbol{x}'}{a} \right) - \frac{1}{2} \sum_{\ell=0}^{5} \left[F_{3}(\boldsymbol{z}_{\ell}) - \sigma_{\ell} F_{2}(\boldsymbol{z}_{\ell}) \right] \right\}.$$

These series typically do not require more than two or three terms for adequate convergence.

A.2 Computation of the Far-Field Pattern

Given a patch with a set of L sample points (u_{ℓ}, v_{ℓ}) along its edge (with $(u_L, v_L) = (u_1, v_1)$), where (u, v) is a point in the curvilinear coordinate system used to describe the patch, one can compute the approximate far-field in the following way. First, sample the loaded element mode $\Psi(u, v)$ at each of the sample points thus forming the set

$$\Psi^{(\ell)} = \Psi(u_\ell, v_\ell).$$

Then the far-field components of the electric field are given by the following formulas.

$$E_{\theta} = jk_0 t (F_x \sin \phi - F_y \cos \phi) \frac{1}{4\pi r} e^{-jk_0 r},$$

$$E_{\phi} = jk_0 t (F_x \cos \phi + F_y \sin \phi) \cos \theta \frac{1}{4\pi r} e^{-jk_0 r},$$

where

$$\begin{split} F &= \sum_{\ell=0}^{L} \hat{\tau}_{\ell} \left[\overline{\Psi}^{(\ell)} j_{0} \left(\frac{1}{2} k_{0} \hat{r} \cdot \Delta r_{\ell} \right) + j \frac{\Delta \Psi^{(\ell)}}{2} j_{1} \left(\frac{1}{2} k_{0} \hat{r} \cdot \Delta r_{\ell} \right) \right] \Delta s_{\ell} e^{j k_{0} \hat{r} \cdot \hat{1}} \\ \overline{\Psi}^{(\ell)} &= \frac{1}{2} \left[\Psi(u_{\ell+1}, v_{\ell+1}) + \Psi(u_{\ell}, v_{\ell}) \right], \\ \Delta \Psi^{(\ell)} &= \Psi(u_{\ell+1}, v_{\ell+1}) - \Psi(u_{\ell}, v_{\ell}), \\ \tau_{\ell} &= x_{\ell} \hat{x} + y_{\ell} \hat{y}, \quad \overline{\tau}_{\ell} = \frac{1}{2} (\tau_{\ell+1} + \tau_{\ell}), \quad \Delta r_{\ell} = \tau_{\ell+1} - \tau_{\ell}, \\ u_{\ell} &= u(x_{\ell}, y_{\ell}), \quad v_{\ell} = v(x_{\ell}, y_{\ell}), \quad \Delta s_{\ell} = |\Delta \tau_{\ell}|, \quad \hat{\tau}_{\ell} = \frac{\Delta \tau_{\ell}}{\Delta s_{\ell}}, \\ \hat{\tau} &= \hat{x} \cos \phi \sin \theta + \hat{y} \sin \phi \sin \theta + \hat{z} \cos \theta, \\ j_{0}(x) &= \frac{\sin x}{x}, \quad j_{1}(x) = \frac{\sin x}{x^{2}} - \frac{\cos x}{x}. \end{split}$$

A.3 The Computation of the Energy Stored in the Cavity

This section deals with the efficient computation of the electric stored energy within a microstrip antenna loaded with N lumped, linear loads. The expression for the loaded mode distribution is given in equation (3) in Section 2. The actual load currents, which are distributed over a finite area, are assumed to be filamentary for the purpose of computing energy. This can be done because while the field itself arising under this assumption has log singularity, the square of this field over the volume of the cavity is integrable. The associated stored energy times ω is given by equation (4) Section 2. This series converges slowly enough that some moderate acceleration is useful. The series is summed, approximately, by extracting a single quasi-static term. This quasi-static term is identical to the 1^{sf}-order quasi-static term of the expansion of the Green's function itself.

The ratio

$$\frac{1}{(k^2 - k_{mn}^2)^2} \approx b_0 \frac{1}{k_{mn}^4} + b_1 \frac{k^2}{k_{mn}^6} \tag{10}$$

for $(m, n) \in A_{\xi}$. The set A_{ξ} is the same as that defined in Section A.1. For the sake of numerical efficiency, the same value of ξ should be used in this computation as that used for computing the field in equation (6) of Section A.1. Using the approximation in (10), one arrives at

$$W_{E} = \frac{1}{2} t \epsilon_{r} \mu_{r}^{2} k_{0}^{3} \eta_{0} \sum_{\ell=0}^{N} \sum_{i=0}^{N} I_{\ell} I_{i}$$

$$\cdot \left\{ \frac{1}{Sk^{4}} + \sum_{\overline{A}_{\ell}} \left(\frac{1}{(k^{2} - k_{mn}^{2})^{2}} - b_{0} \frac{1}{k_{mn}^{2}} - b_{1} \frac{k^{2}}{k_{mn}^{4}} \right) \psi_{mn}(\boldsymbol{r}_{i}) \psi_{mn}(\boldsymbol{r}_{\ell})$$

$$- b_{0} G_{1}(\boldsymbol{r}_{i} | \boldsymbol{r}_{\ell}) - b_{1} k^{2} G_{2}(\boldsymbol{r}_{i} | \boldsymbol{r}_{\ell}) \right\},$$

where

$$G_2(\boldsymbol{r}|\boldsymbol{r}') = -\sum_{\boldsymbol{A}n} \frac{\psi_{mn}(\boldsymbol{r})\psi_{mn}(\boldsymbol{r}')}{k_{mn}^6}$$

The computation of $G_1(r|r')$ is discussed in Section A.1. The computation of $G_2(r|r')$ could be handled in the same way as the computation of the lower-order quasistatic terms, but this is too tedious a computation. Instead, $G_2(r|r')$ is summed directly. The coefficients b_0 and b_1 are the solution of the minimax problem,

$$\min_{b_0, b_1} \left\{ \max_{0 \le x \le 1/\xi^2} |\eta(x)| \right\},\,$$

where

$$\eta(x) = \frac{1}{(1-x)^2} - b_0 - b_1 x$$

A plot of $\eta(x)$ versus x will show that the minimax solution will satisfy

$$\eta(0)=\eta(1/\xi^2)$$

and

$$\eta(0)=-\eta(x_{\max}),$$

where x_{max} satisfies

$$\frac{d}{dx}\eta(x) = \frac{2}{(1-x)^3} - b_1 = 0.$$

The solution to this is

$$x_{\max} = 1 - \left(\frac{2}{b_1}\right)^{1/3}.$$

The solution to the minimax problem is

$$b_1 = \left(\frac{1}{(1-1/\xi^2)^2 - 1}\right)\xi^2$$
$$b_0 = \frac{1}{2}\left(1 - b_1 + 3\left(\frac{b_1}{2}\right)^{2/3}\right)$$

For $\xi = 2$, these parameters are

$$b_0 = 0.958$$

and

$$b_1 = 3.111.$$

This approximation yields a maximum error of about 4%.

The next problem is to find $G_2(\tau | \tau')$. What is the error if $G_2(\tau | \tau')$ were only summed over \overline{A}_{ξ} ? If $\xi = 2$, then a typical relative error level would be no worse than

 $2^{-4} \approx 0.06.$

This is because k_{\max} is typically greater than or equal to the smallest non-zero k_{mn} . Contributions to the sum outside of \overline{A}_{ξ} are at least 2^{-6} times as small as the contribution due to the smallest k_{mn} . In the worst case, all contributions outside of \overline{A}_{ξ} add in phase (when the source and observation points coincide) in which case the sum can be approximated by a continuous integral over wavenumber. This accounts for the exponent of 4 in the previous equation. This approximation of truncating $G_2(\tau | \tau')$ to just a sum over \overline{A}_{ξ} should be adequate. Under this approximation, the expression for W_E becomes

$$W_{E} = \frac{1}{2} t \epsilon_{r} \mu_{r}^{2} k_{0}^{3} \eta_{0} \sum_{\ell=0}^{N} \sum_{i=0}^{N} I_{\ell} I_{i}$$

$$\left\{ \frac{1}{Sk^{4}} + \sum_{\overline{A}_{\ell}} \left(\frac{1}{(k^{2} - k_{mn}^{2})^{2}} - b_{0} \frac{1}{k_{mn}^{4}} \right) \psi_{mn}(r_{i}) \psi_{mn}(r_{\ell}) - b_{0} G_{1}(r_{i}|r_{\ell}) \right\}.$$

MISSION of

かんむんむんむん

Rome Air Development Center

RADC plans and executes research, development, test and selected acquisition programs in support of Command, Control, Communications and Intelligence (C³I) activities. Technical and engineering support within areas of competence is provided to ESD Program Offices (POs) and other ESD elements to perform effective acquisition of C³I systems. The areas of technical competence include communications, command and control, battle management, information processing, surveillance sensors, intelligence data collection and handling, sclid state sciences, electromagnetics, and propagation, and electronic, maintainability, and compatibility.

LOLOCKACKA

ଡ଼ୄ୵ଽଡ଼୵ଽଡ଼୵ଽଡ଼୵ଡ଼୵ଡ଼ୄୄୄୄୄୄୄୄୄୄୄ୰ୄ

ୢ୶*୴ୠ*ୄ୶ଡ଼ୢ୶ଡ଼ୢ୷ଡ଼ୄ୷ଡ଼ୢ୷ଡ଼ୢୄ୷ଡ଼ୄୢୄ୶ଡ଼ୄ

